

Part Number:

SnapLED

XSDG93W

PRELIMINARY SPEC



Features:

- HIGH LUMINANCE OUTPUT.
- DESIGN FOR HIGH CURRENT OPERATION.
- SOLDERLESS MOUNTING TECHNIQUE.
- •LOW POWER CONSUMPTION.
- •LOW THERMAL RESISTANCE.
- •LOW PROFILE.
- PACKAGED IN TUBES FOR USE WITH AUTOMATIC INSERTION EQUIPMENT.
- RoHS COMPLIANT.



ATTENTION OBSERVE PRECAUTIONS FOR HANDLING ELECTROSTATIC DISCHARGE SENSITIVE DEVICES

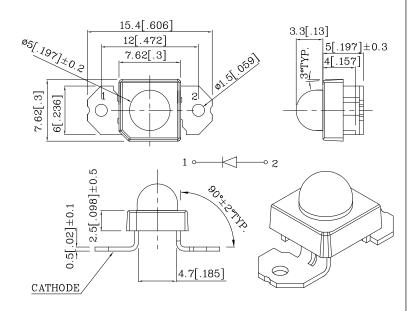
Benefits

- *Rugged Lighting Products.
- *Electricity savings.
- *Maintenance savings.
- *Environmental Conformance.

Typical Applications

- *Automotive Exterior Lighting.
- *Solid State Lighting and Signaling.

Absolute Maximum Ra (TA=25°C)	DG (AlInGaN)	Unit		
Reverse Voltage	$V_{\rm R}$	5	V	
DC Forward Current	IF	30	mA	
Power Dissipation	Рт	126	mW	
Operating Temperature	TA	-40 ~ +85		
Storage Temperature	Tstg	-55 ~ +85	°C	
Electrostatic Discharge T (HBM)	450	V		



Notes:

- 1. All dimensions are in millimeters (inches).
- 2. Tolerance is $\pm 0.25(0.01")$ unless otherwise noted.
- 3. Specifications are subject to change without notice.





Operating Characteristics (TA=25°C)	DG (AlInGaN)	Unit	
Forward Voltage (Typ.) (Ir=30mA)	VF	3.4	V
Forward Voltage (Max.) (IF=30mA)	V_{F}	4.2	V
Reverse Current (Max.) (VR=5V)	IR	10	uA
Wavelength Of Peak Emission (Typ.) (IF=30mA)	λΡ	515	nm
Wavelength Of Dominant Emission (Typ.) (IF=30mA) [1]	λ D	525	nm
Spectral Line Full Width At Half-Maximum (Typ.) (IF=30mA)	Δλ	30	nm
Capacitance (Typ.) (VF=0V, f=1MHz)	C	45	pF
Thermal Resistance (Typ.)	Rθj -pin	150	°C/W

1. The dominant wavelength is derived from the CIE Chromaticity Diagram and represents the perceived color of the device.

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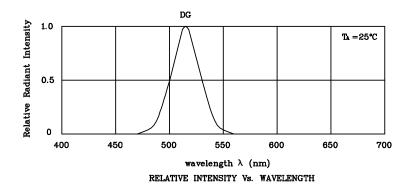


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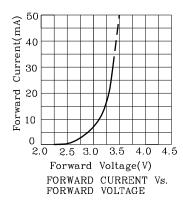
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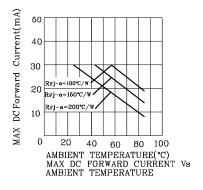
Part Number	Emitting Color	Emitting Material	Lens-color	Inter (IF=3	inous nsity (0mA) cd	Luminous Flux (IF=30mA) mlm	Wavelength nm λ P	Viewing Angle 2 0 1/2
				Min.	Тур.	Typ.		
XSDG93W	Green	AlInGaN	Water Clear	4700	7490	4200	515	30°

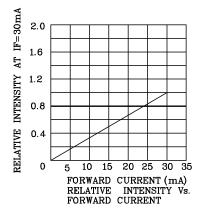
1.LUMINOUS INTENSITY IS MEASURED WITH AN INTEGRATING SPHERE AFTER THE DEVICE HAS STABILIZED. 2. θ 1/2 IS THE ANGLE FROM OPTICAL CENTERLINE WHERE THE LUMINOUS INTENSITY IS 1/2 THE OPTICAL CENTERLINE VALUE.

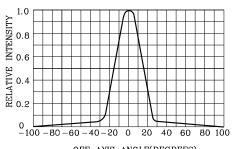


♦ DG









OFF AXIS ANGLE(DEGREES)
RELATIVE INTENSITY VS OFF AXIS ANGLE

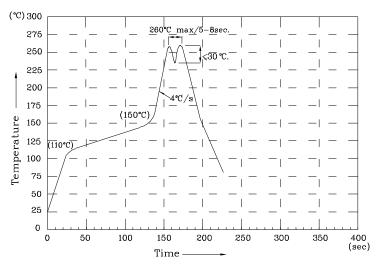
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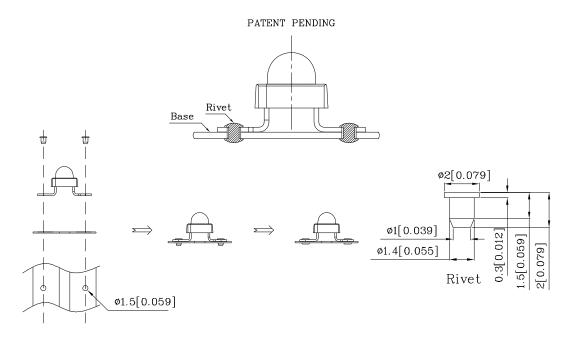


Wave Soldering Profile For Lead-free Through-hole LED.



NOTES:

- 1.Recommend the wave temperature 245°C~260°C.The maximum soldering temperature should be less than 260°C.
- 2.Do not apply stress on epoxy resins when temperature is over 85 degree°C.
- 3. The soldering profile apply to the lead free soldering (Sn/Cu/Ag alloy).
- 4. No more than once.



Remarks:

If special sorting is required (e.g. binning based on forward voltage, Luminous intensity / luminous flux, or wavelength), the typical accuracy of the sorting process is as follows:

- 1. Wavelength: +/-1nm
- 2. Luminous intensity / luminous flux: +/-15%
- 3. Forward Voltage: \pm -0.1V

Note: Accuracy may depend on the sorting parameters.

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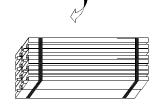
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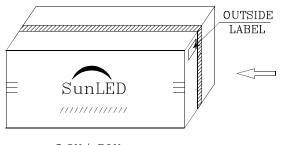


65PCS / IC TUBE

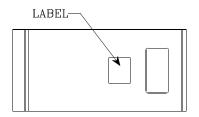


520pcs / 8pcs IC TUBE

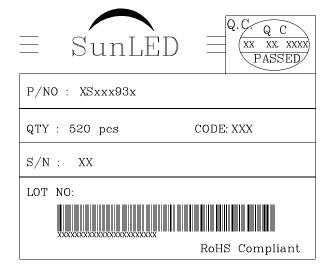




5.2K/ BOX



8pcs IC TUBE / BAG



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